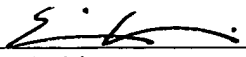


REMARKS

In response to the *Notice of Incomplete Reply* dated January 2, 2002, copy enclosed, submitted herewith is a amendment to correct minor typographical errors in the specification. Applicant wishes to follow option III in the *Notice of Incomplete Reply* in that Fig. 9C is not included in the present application. By the above amendment this error has been corrected.

Examination on the merits is respectfully requested.

Respectfully submitted,



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VERSION WITH MARKINGS TO SHOW CHANGES MADE

IN THE SPECIFICATION:

Please amend the specification as follows:

Page 17, Paragraph 6, continuing on Page 18

FIG. 9A to FIG. [9C] **9B** are cross-sectional views illustrating some steps in the method of manufacturing a semiconductor device according to the fourth embodiment, from the removal of an unreacted second cobalt film up to the formation of a fourth silicide film.